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## 2SD0874, 2SD0874A (2SD874, 2SD874A)

### Silicon NPN epitaxial planar type

#### For low-frequency power amplification

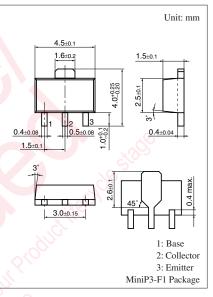
Complementary to 2SB0766 (2SB766) and 2SB0766A (2SB766A)

#### Features

- $\bullet$  Large collector power dissipation  $P_{\rm C}$
- $\bullet$  Low collector-emitter saturation voltage  $V_{\mbox{CE(sat)}}$
- Mini power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

Parameter	Symbol Rating		Unit	
Collector-base voltage	2SD0874	V <sub>CBO</sub>	30	V
(Emitter open)	2SD0874A		60	
Collector-emitter voltage	2SD0874	V <sub>CEO</sub>	25	V
(Base open)	2SD0874A		50	
Emitter-base voltage (Collector open)		V <sub>EBO</sub>	5	V
Collector current		I <sub>C</sub>	1	А
Peak collector current		I <sub>CP</sub>	1.5	А
Collector power dissipation *		P <sub>C</sub>	1	W
Junction temperature		Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	€°C	





- Marking Symbol:
  - 2SD0874: Z
    - 2SD0874A: Y

Note) \*: Printed circuit board: Copper foil area of 1 cm<sup>2</sup> or more, and the board thickness of 1.7 mm for the collector portion

#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage	2SD0874	V <sub>CBO</sub>	$I_{\rm C} = 10 \ \mu A, I_{\rm E} = 0$	30	3		V
(Emitter open)	2SD0874A			60			
Collector-emitter voltage	2SD0874	V <sub>CEO</sub>	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	25			V
(Base open)	2SD0874A		Q. S. Mas Mos	50			
Emitter-base voltage (Colle	ctor open)	V <sub>EBO</sub>	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	5			V
Collector-base cutoff current (E	Emitter open)	I <sub>CBO</sub>	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μΑ
Forward current transfer ratio *1		h <sub>FE1</sub> *2	$V_{CE} = 10 \text{ V}, I_C = 500 \text{ mA}$	85		340	_
		h <sub>FE2</sub>	$V_{CE} = 5 V, I_C = 1 A$	50			
Collector-emitter saturation	voltage *1	V <sub>CE(sat)</sub>	$I_{C} = 500 \text{ mA}, I_{B} = 50 \text{ mA}$		0.2	0.4	V
Base-emitter saturation vol	tage *1	V <sub>BE(sat)</sub>	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		0.85	1.2	V
Transition frequency		f <sub>T</sub>	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance		C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			20	pF
(Common base, input open circuited)							

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

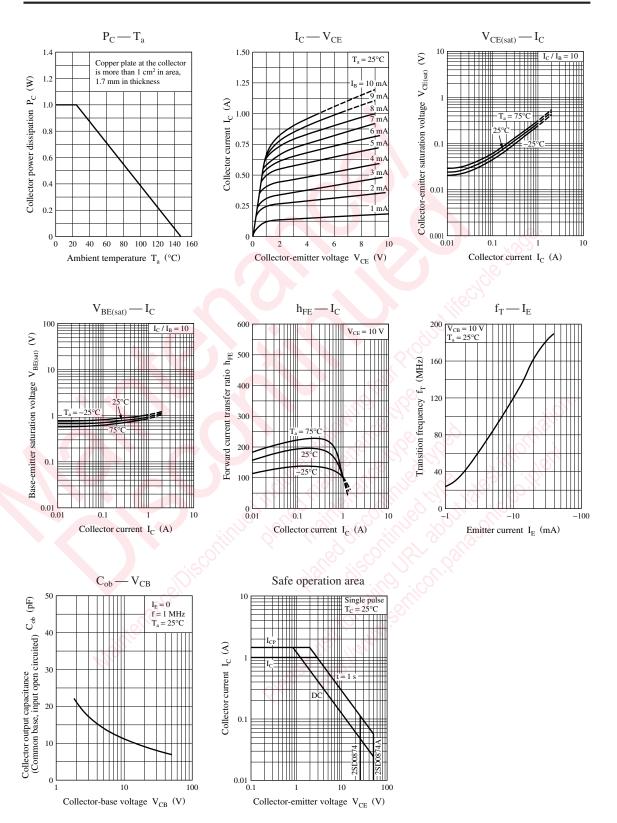
2. \*1: Pulse measurement

*2: Rank classification	
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Rank	Q	R	S
$h_{\rm FE1}$	85 to 170	120 to 240	170 to 340

Note) The part numbers in the parenthesis show conventional part number.

### **Panasonic**



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